ABSTRACT OF THE DISCLOSURE

MULTI-WAVELENGTH LIGHT-EMITTING SEMICONDUCTOR DEVICES

A multi-wavelength light-emitting semiconductor device and a method of fabricating the same are disclosed. The semiconductor device includes a substrate, a first reflector on the substrate, a light emission layer on the first reflector, second reflectors on corresponding active regions; and apertures on corresponding active regions. The light emission layer includes active regions. Each of the active regions includes a primary emission wavelength different from each other.

Publish with Figure 1